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Bulletin I25200 rev.B 04/00

International
IOR Rectifier

ST3230C..R SERIES

PHASE CONTROL THYRISTORS

Hockey Puk Version

Features

- Double side cooling
- High surge capability
- High mean current
- Fatigue free

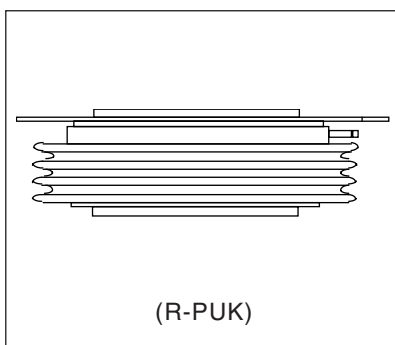
Typical Applications

- DC motor controls
- Controlled DC power supplies
- AC controllers

Major Ratings and Characteristics

Parameters	ST3230C..R	Units
$I_{T(AV)}$	2785	A
@ T_C	80	°C
$I_{T(AV)}$	3360	A
@ T_{hs}	55	°C
$I_{T(RMS)}$	5970	A
@ T_{hs}	25	°C
I_{TSM}	@ 50Hz	61200
	@ 60Hz	64000
I^2t	@ 50Hz	18730
	@ 60Hz	17000
V_{DRM}/V_{RRM}	1000 to 1800	V
t_q	typical	500
T_J	max.	125
		°C

3360A



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ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{DRM}/V_{RRM} , max. repetitive peak and off-state voltage V	V_{RSM} , maximum non-repetitive peak voltage V	I_{DRM}/I_{RRM} max. @ $T_C = 125^\circ\text{C}$ mA
ST3230C..R	10	1000	1100	250
	12	1200	1300	
	14	1400	1500	
	16	1600	1700	
	18	1800	1900	

On-state Conduction

Parameter		ST3230C..R	Units	Conditions		
$I_{T(AV)}$	Max. average on-state current @ Case temperature	2785 (1720)	A	180° conduction, half sine wave double side (single side [anode side]) cooled		
		80	°C			
$I_{T(AV)}$	Max. average on-state current @ Heatsink temperature	3360 (1360)	A			
		55 (85)	°C			
$I_{T(RMS)}$	Max. RMS on-state current	5970	A	DC @ 25°C heatsink temperature double side cooled		
I_{TSM}	Max. peak, one-cycle non-repetitive surge current	61200	A	t = 10ms	No voltage	Sinusoidal half wave, Initial $T_C = 125^{\circ}\text{C}$
		64000		t = 8.3ms	reapplied	
		49000		t = 10ms	50% V_{RRM}	
		51300		t = 8.3ms	reapplied	
I^2t	Maximum I^2t for fusing	18730	KA^2s	t = 10ms	No voltage	
		17000		t = 8.3ms	reapplied	
		12000		t = 10ms	50% V_{RRM}	
		10920		t = 8.3ms	reapplied	
$V_{T(TO)}$	Max. value of threshold voltage	0.92	V	$T_J = T_J \text{ max.}$		
r_t	Max. value of on-state slope resistance	0.09	mΩ	$T_J = T_J \text{ max.}$		
V_{TM}	Max. on-state voltage	1.3	V	$I_{pk} = 2900\text{A}$, $T_C = 25^{\circ}\text{C}$		
I_L	Typical latching current	300	mA	$T_J = 25^{\circ}\text{C}$, $V_D = 5\text{V}$		

Switching

Parameter	ST3230C..R	Units	Conditions
di/dt Max. repetitive 50Hz (no repetitive) rate of rise of turned-on current	150 (300)	A/ μs	From 67% V_{DRM} to 1000A gate drive 10V, 5 Ω , $t_r = 0.5\mu\text{s}$ to 1A, $T_J = T_J \text{ max.}$
t_d Maximum delay time	4.5	μs	Gate drive 30V, 15 Ω , $V_d = 67\% V_{DRM}$, $T_J = 25^\circ\text{C}$ Rise time 0.5 μs
t_q Typical turn-off time	500		$I_T = 1000\text{A}$, $t_p = 1\text{ms}$, $T_J = T_J \text{ max.}$, $V_{RM} = 50\text{V}$, $di_{FR}/dt = 2\text{A}/\mu\text{s}$, $V_{DR} = 67\% V_{DRM}$, $dv_{DR}/dt = 8\text{V}/\mu\text{s}$ linear

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Blocking

Parameter	ST3230C..R	Units	Conditions
dv/dt Maximum linear rate of rise of off-state voltage	500	V/ μ s	$T_J = T_J \text{ max. to } 67\% \text{ rated } V_{DRM}$
I_{RRM} I_{DRM} Max. peak reverse and off-state leakage current	250	mA	$T_J = 125^\circ\text{C}$ rated V_{DRM}/V_{RRM} applied

Triggering

Parameter	ST3230C..R	Units	Conditions
P_{GM} Maximum peak gate power	150	W	$t_p = 100\mu\text{s}$
$P_{G(AV)}$ Maximum average gate power	10		
I_{GM} Max. peak positive gate current	30	A	Anode positive with respect to cathode
V_{GM} Max. peak positive gate voltage	30	V	Anode positive with respect to cathode
$-V_{GM}$ Max. peak negative gate voltage	0.25	V	Anode negative with respect to cathode
I_{GT} Maximum DC gate current required to trigger	400	mA	$T_C = 25^\circ\text{C}$, $V_{DRM} = 5V$
V_{GT} Maximum gate voltage required to trigger	4	V	$T_C = 25^\circ\text{C}$, $V_{DRM} = 5V$
V_{GD} DC gate voltage not to trigger	0.25	V	$T_C = 125^\circ\text{C}$ Max. gate current/voltage not to trigger is the max. value which will not trigger any unit with rated V_{DRM} anode-to-cathode applied

Thermal and Mechanical Specification

Parameter	ST3230C..R	Units	Conditions
$T_J \text{ max.}$ Max. operating temperature	125	$^\circ\text{C}$	On-state (conducting)
T_{stg} Max. storage temperature range	-55 to 125		
R_{thJ-C} Thermal resistance, junction to case	0.019 0.0095	K/W	DC operation single side cooled DC operation double side cooled
$R_{th(C-h)}$ Thermal resistance, case to heatsink	0.004 0.002	K/W	Single side cooled Double side cooled
F Mounting force $\pm 10\%$	43000 (4400)	N (Kg)	Clamping force 43KN with mounting compound
wt Approximate weight	1600	g	
Case style	(R-PUK)		See Outline Table

ΔR_{thJ-C} Conduction

(The following table shows the increment of thermal resistance R_{thJ-C} when devices operate at different conduction angles than DC)

Conduction angle	Single side	Double side	Units	Conditions
180°	0.0010	0.0010	K/W	$T_J = T_J \text{ max.}$
120°	0.0017	0.0017		
60°	0.0044	0.0044		

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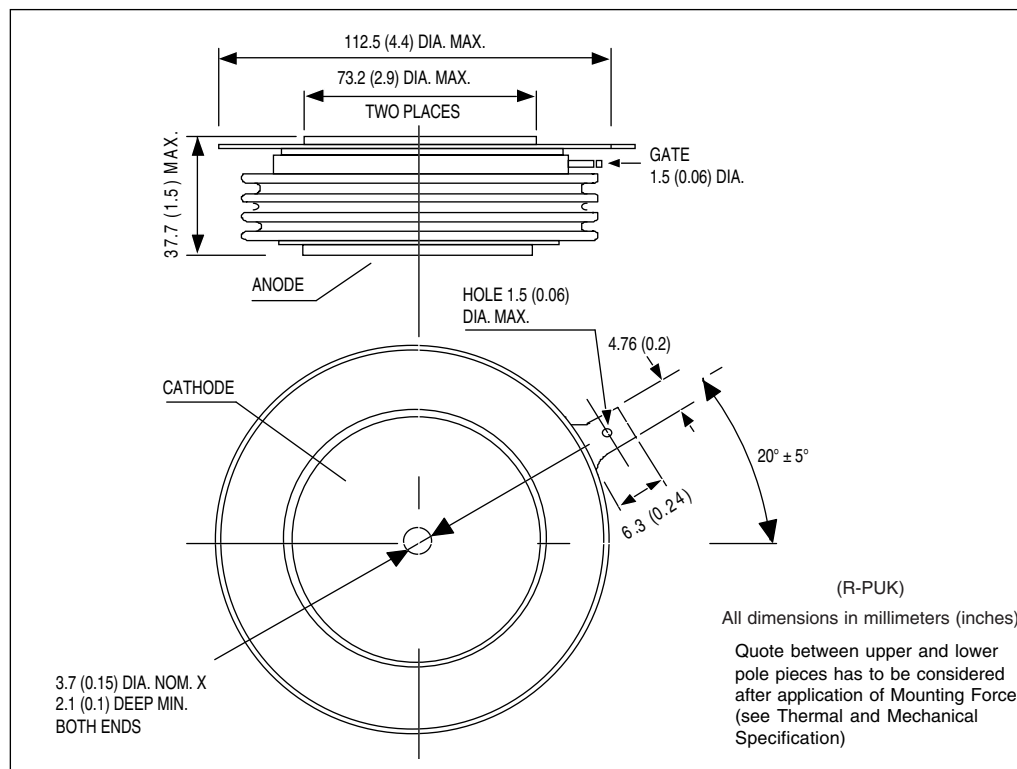
Ordering Information Table

Device Code

ST	323	0	C	18	R	1	
1	2	3	4	5	6	7	8

- 1** - Thyristor
- 2** - Essential part number
- 3** - 0 = Converter grade
- 4** - C = Ceramic Puk
- 5** - Voltage code: Code x 100 = V_{RRM} (See Voltage Rating Table)
- 6** - R = Puk Case
- 7** - 0 = Eyelet terminals (Gate and Auxiliary Cathode Unsoldered Leads)
1 = Fast-on terminals (Gate and Auxiliary Cathode Unsoldered Leads)
2 = Eyelet terminals (Gate and Auxiliary Cathode Soldered Leads)
3 = Fast-on terminals (Gate and Auxiliary Cathode Soldered Leads)
- 8** - Critical dv/dt: None = 500V/ μ sec (Standard selection)
L = 1000V/ μ sec (Special selection)

Outline Table



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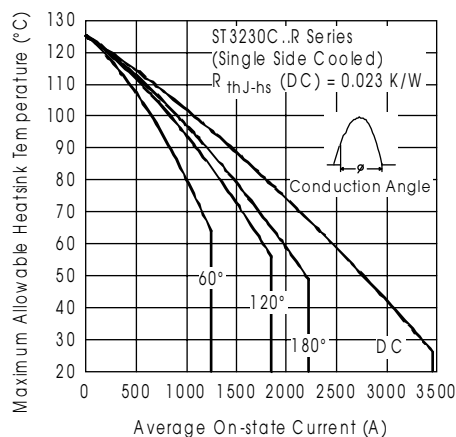


Fig. 1 - Current Ratings Characteristics

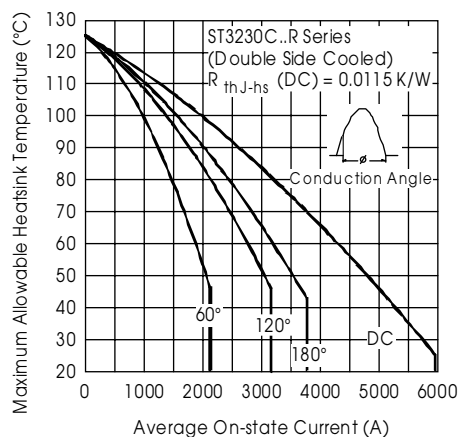


Fig. 2 - Current Ratings Characteristics

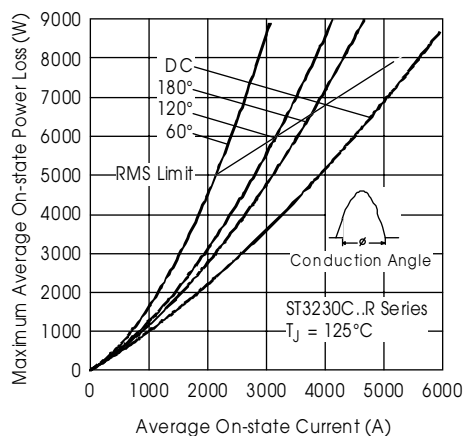


Fig. 3 - On-state Power Loss Characteristics

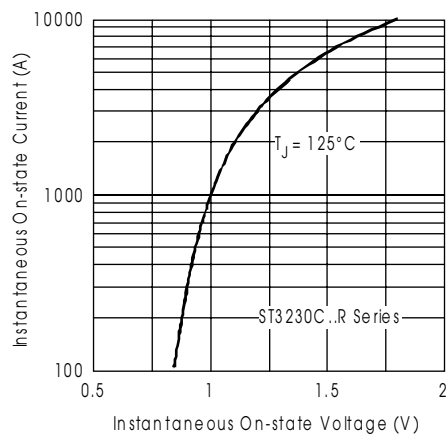


Fig. 4 - On-state Voltage Drop Characteristics

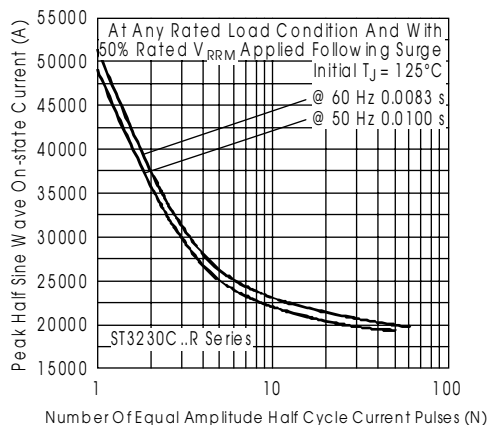


Fig. 5 - Maximum Non-Repetitive Surge Current

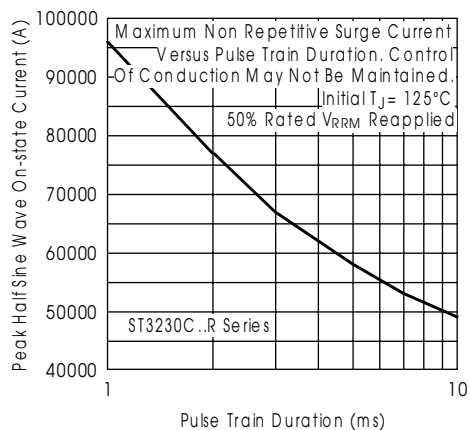


Fig. 6 - Maximum Non-Repetitive Surge Current

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